

BC182LB

NPN General Purpose Amplifier

- This device is designed for general purpose amplifier application at collector currents to 100mA.
- · Sourced from process 10.



Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units V	
V _{CEO}	Collector-Emitter Voltage	50		
V _{CBO}	Collector-Base Voltage	60	V	
V _{EBO}	Emitter-Base Voltage	6	V	
Ic	Collector Current - Continuous	100	mA	
T _{J.} T _{STG}	Storage Junction Temperature Range	- 55 ~ 150	°C	

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Chara	cteristics					
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_C = 2mA, I_B = 0$ 50				V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{C} = 10 \mu A, I_{E} = 0$	60			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 100µA, I _C = 0	6			٧
I _{CBO}	Collector Cut-off Current	$V_{CB} = 50V, V_{BE} = 0$			15	nA
I _{EBO}	Emitter-Base Leakage Current	V _{EB} = 4V, I _E = 0			15	nA
On Chara	cteristics				VII	
h _{FE}	DC Current Gain	V _{CE} = 5V, I _C = 10 µ A V _{CE} = 5V, I _C = 100mA	40 80			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 10mA, I _B = 0.5mA I _C = 100mA, I _B = 5mA			0.25 0.6	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = 100mA, I _B = 5mA			1.2	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 5V$, $I_C = 2mA$	0.55		0.7	V
Dynamic (Characteristics					
f _T	Current Gain Bandwidth Product	V _{CE} = 5V, I _C = 10mA, f = 100MHz 150				MHz
Cob	Output Capacitance	V _{CE} = 10V, I _C = 0, f = 1MHz			5	pF
h _{fe}	Small Signal Current Gain	V _{CE} = 5V, I _C = 2mA, f = 1KHz 240			500	
NF	Noise Figure	$V_{CE} = 5V, I_{C} = 0.2mA$ $R_{S} = 2K\Omega, f = 1KHz, BW = 200Hz$			10	dB

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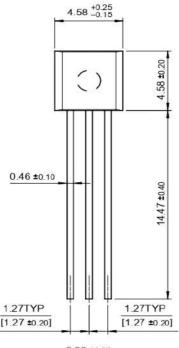
Thermal Characteristics $T_A=25^{\circ}\mathrm{C}$ unless otherwise noted

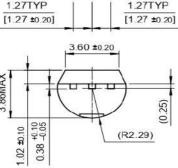
Symbol	Parameter	Max.	Units
PD	Total Device Dissipation @T _A =25°C	350	mW
	Derate above 25°C	2.8	mW/°C
Reja	Thermal Resistance, Junction to Ambient	357	mW/°C
Reuc	Thermal Resistance, Junction to Case	125	°C/W

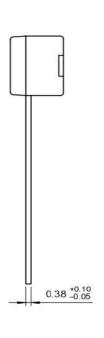
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Package Dimensions

TO-92







Dimensions in Millimeters

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